

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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2SA1494

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC3858)

Application: Audio and General Purpose

■Absolute maximum ratings (Ta=25°C)

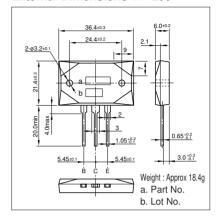
Symbol	Ratings	Unit		
Vсво	-200	V		
VCEO	-200	V		
VEBO	-6	V		
Ic	–17	Α		
Ів	-5	Α		
Pc	200(Tc=25°C)	W		
Tj	150	°C		
Tsta	-55 to +150	°C.		

■Electrical Characteristics

■Electrical Cl	naracteristics	(Ta=25°C)		
Symbol	Conditions	Ratings	Unit	
Ісво	Vcb=-200V	-100max	μΑ	
I EBO	VEB=-6V	-100max	μΑ	
V(BR)CEO	Ic=-50mA	–200min	V	
hfE	VCE=-4V, IC=-8A	50min*		
VcE(sat)	Ic=-10A, IB=-1A	-2.5max	V	
fτ	Vce=-12V, IE=1A	20typ	MHz	
Сов	VcB=-10V, f=1MHz	500typ	pF	

*hFE Rank Y(50 to 100), P(70 to 140), G(90 to 180)

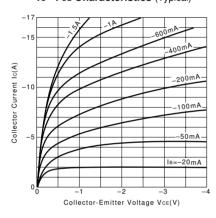
External Dimensions MT-200



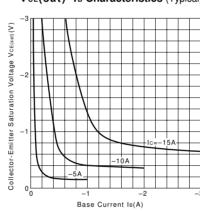
Typical Switching Characteristics (Common Emitter)

= Typical Owitching Characteristics (Common Emitter)										
	Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (A)	I _{B2} (A)	ton (µs)	tstg (µs)	tf (μs)
	-40	4	-10	-10	5	-1	1	0.6typ	0.9typ	0.2typ

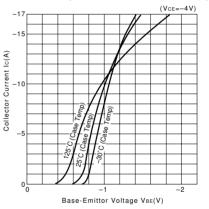
Ic-VcE Characteristics (Typical)



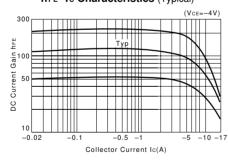
VcE(sat)-IB Characteristics (Typical)



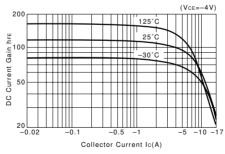
Ic-VBE Temperature Characteristics (Typical)



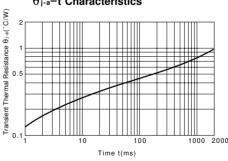
hfe-Ic Characteristics (Typical)



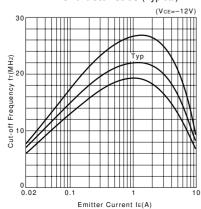
hfe-Ic Temperature Characteristics (Typical)



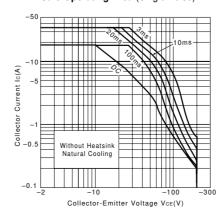
 θ_{j-a} -t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

